

PSMN085-150K

N-channel TrenchMOS SiliconMAX standard level FET

Rev. 3 — 22 December 2011

Product data sheet

1. Product profile

1.1 General description

SiliconMAX standard level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Suitable for high frequency applications due to fast switching characteristics

1.3 Applications

- Computer motherboards
- DC-to-DC convertors

Switched-mode power supplies

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit		
V_{DS}	drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 150 \text{ °C}$	-	-	150	V		
I _D	drain current	$T_{sp} = 80 ^{\circ}C$; see <u>Figure 1</u> ; see <u>Figure 3</u>	-	-	3.5	Α		
P _{tot}	total power dissipation	T _{sp} = 80 °C; see <u>Figure 2</u>	-	-	3.5	W		
Static char	acteristics							
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 3.5 \text{ A}; T_j = 25 \text{ °C};$ see <u>Figure 9</u> ; see <u>Figure 10</u>	-	67	85	mΩ		
Dynamic c	Dynamic characteristics							
Q_{GD}	gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 4.1 \text{ A}; V_{DS} = 75 \text{ V};$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 11}}{ constant of the second $	-	12	17	nC		



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	00.00.00	
2	S	source	8 <u> </u>	D
3	S	source		
4	G	gate		
5	D	drain	1	mbb076 S
6	D	drain	SOT96-1 (SO8)	
7	D	drain		
8	D	drain		

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PSMN085-150K	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V_{DS}	drain-source voltage	$T_j \ge 25 \text{ °C}; T_j \le 150 \text{ °C}$	-	150	V	
V_{GS}	gate-source voltage		-20	20	V	
I_D	drain current	$T_{sp} = 80 ^{\circ}C$; see <u>Figure 1</u> ; see <u>Figure 3</u>	-	3.5	Α	
I_{DM}	peak drain current	T_{sp} = 25 °C; pulsed; $t_p \le 10 \mu s$; see <u>Figure 3</u>	-	40	Α	
P _{tot}	total power dissipation	T _{sp} = 80 °C; see <u>Figure 2</u>	-	3.5	W	
T _{stg}	storage temperature		-55	150	°C	
Tj	junction temperature		-55	150	°C	
Source-drain diode						
I _S	source current	$T_{sp} = 80 ^{\circ}C$	-	3.1	Α	
I _{SM}	peak source current	$T_{sp} = 25$ °C; pulsed; $t_p \le 10 \mu s$	-	40	Α	

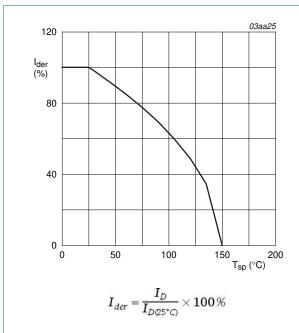


Fig 1. Normalized continuous drain current as a function of solder point temperature

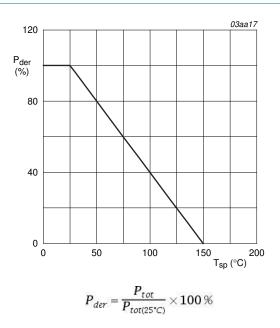
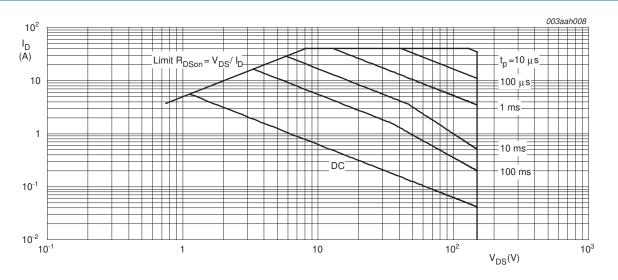


Fig 2. Normalized total power dissipation as a function of solder point temperature



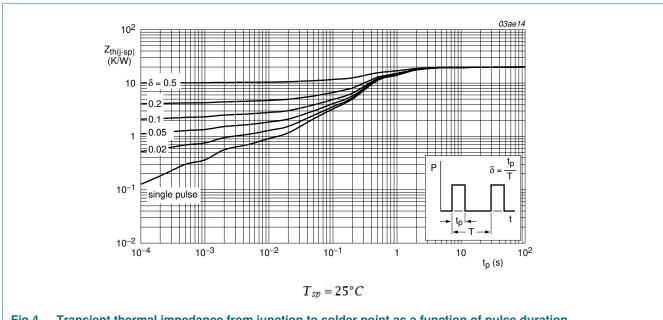
 $T_{sp} = 25$ °C; I_{DM} is single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

Thermal characteristics

Thermal characteristics Table 5.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	mounted on a metal clad substrate; see Figure 4	-	-	20	K/W

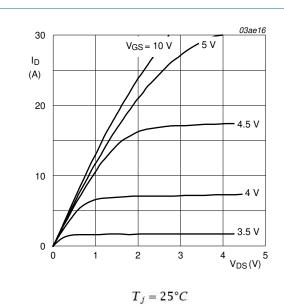


Transient thermal impedance from junction to solder point as a function of pulse duration

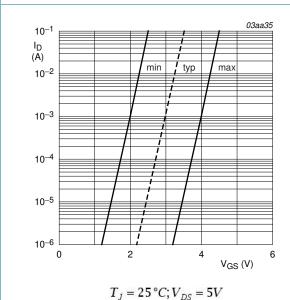
6. Characteristics

Table 6. Characteristics

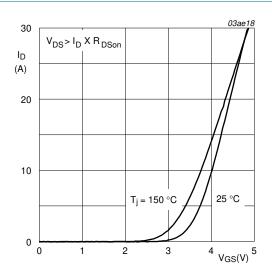
Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	150	180	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = -55$ °C; see Figure 8	-	-	6	V
		$I_D = 1$ mA; $V_{DS} = V_{GS}$; $T_j = 25$ °C; see Figure 8	2	-	4	V
		I_D = 1 mA; V_{DS} = V_{GS} ; T_j = 150 °C; see <u>Figure 8</u>	1.2	-	-	V
I_{DSS}	drain leakage current	V_{DS} = 120 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μΑ
		$V_{DS} = 150 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	0.5	mA
I_{GSS}	gate leakage current	$V_{GS} = 20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	100	nA
		$V_{GS} = -20 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	100	nA
R_{DSon}	R _{DSon} drain-source on-state resistance	V_{GS} = 10 V; I_D = 3.5 A; T_j = 150 °C; see <u>Figure 9</u> ; see <u>Figure 10</u>	-	161	204	mΩ
		V_{GS} = 10 V; I_D = 3.5 A; T_j = 25 °C; see <u>Figure 9</u> ; see <u>Figure 10</u>	-	67	85	mΩ
Dynamic o	characteristics					
Q _{G(tot)}	total gate charge	$I_D = 4.1 \text{ A}; V_{DS} = 75 \text{ V}; V_{GS} = 10 \text{ V};$	-	40	-	nC
Q_{GS}	gate-source charge	T _j = 25 °C; see <u>Figure 11</u>	-	4	-	nC
Q_{GD}	gate-drain charge		-	12	17	nC
C _{iss}	input capacitance	$V_{DS} = 25 V; V_{GS} = 0 V; f = 1 MHz;$	-	1310	-	рF
C _{oss}	output capacitance	T _j = 25 °C; see <u>Figure 12</u>	-	170	-	рF
C _{rss}	reverse transfer capacitance		-	80	-	рF
t _{d(on)}	turn-on delay time	$V_{DS} = 75 \text{ V}; R_L = 75 \Omega; V_{GS} = 10 \text{ V};$	-	13	30	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 \text{ °C}; I_D = 1 A$	-	17	30	ns
t _{d(off)}	turn-off delay time		-	52	80	ns
t _f	fall time		-	30	45	ns
9fs	transfer conductance	V_{DS} = 15 V; I_{D} = 4.1 A; T_{j} = 25 °C; see <u>Figure 14</u>	-	14	-	S
Source-dr	rain diode					
V_{SD}	source-drain voltage	$I_S = 2.3 \text{ A}$; $V_{GS} = 0 \text{ V}$; $T_j = 0 \text{ °C}$; see Figure 13	-	0.7	1.1	V
t _{rr}	reverse recovery time	$I_S = 4.1 \text{ A}$; $dI_S/dt = -100 \text{ A/}\mu\text{s}$;	-	100	-	ns
Qr	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; T_j = 25 \text{ °C}$	-	0.36	-	μC



Output characteristics: drain current as a Fig 5. function of drain-source voltage; typical values



Sub-threshold drain current as a function of Fig 7. gate-source voltage



 $T_j = 25^{\circ}C$ and $150^{\circ}C$; $V_{DS} > I_D \times R_{DSon}$

Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

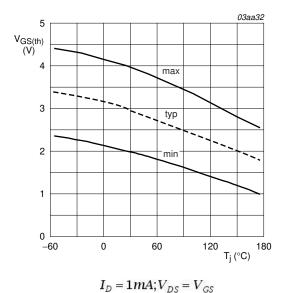


Fig 8. Gate-source threshold voltage as a function of junction temperature

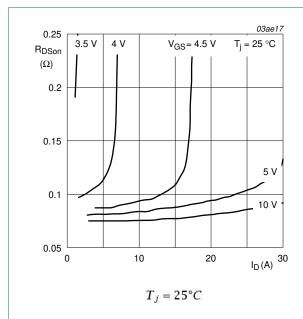


Fig 9. Drain-source on-state resistance as a function of drain current; typical values

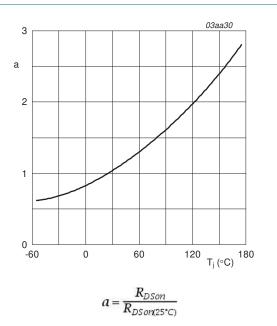
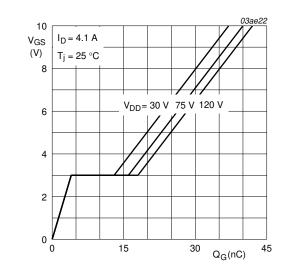
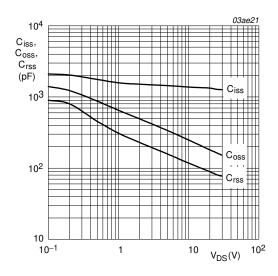


Fig 10. Normalized drain-source on-state resistance factor as a function of junction temperature



 $I_D = 4.1A; V_{DS} = 30V, 75V$ and 120V

Fig 11. Gate-source voltage as a function of gate charge; typical values



 $V_{GS} = 0V; f = 1MHz$

Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

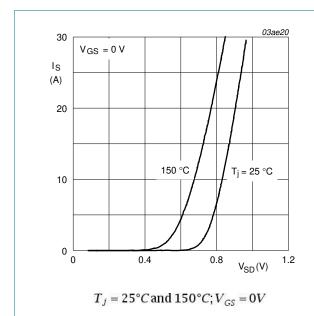


Fig 13. Source current as a function of source-drain voltage; typical values

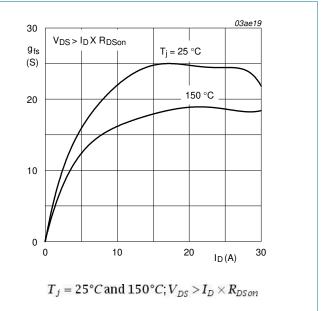
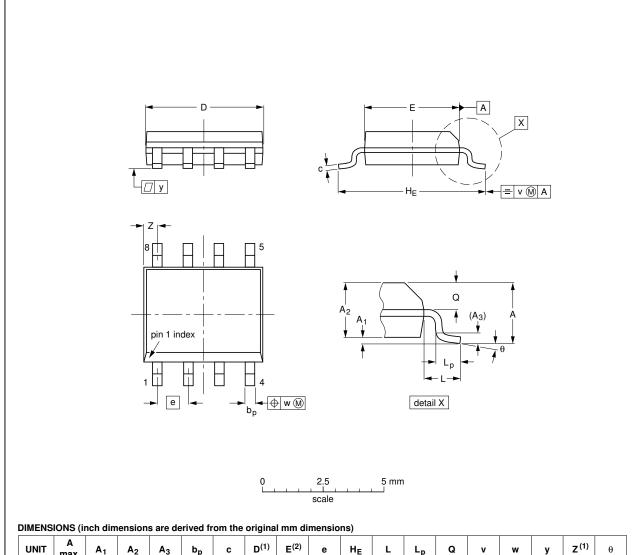


Fig 14. Forward transconductance as a function of drain current; typical values

7. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.20 0.19	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT96-1	076E03	MS-012				99-12-27 03-02-18

Fig 15. Package outline SOT96-1 (SO8)

PSMN085-150K

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8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PSMN085-150K v.3	20111222	Product data sheet	-	PSMN085_150K v.2
Modifications:				
PSMN085_150K v.2	20100301	Product data sheet	-	PSMN085_150K v.1

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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PSMN085-150K

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